| ΡΛΝ | ĴΪΤ |
|-----|-----------|
| | SEMI |
| | CONDUCTOR |

30V N-Channel Enhancement Mode MOSFET

Voltage

Current 152 A

Features

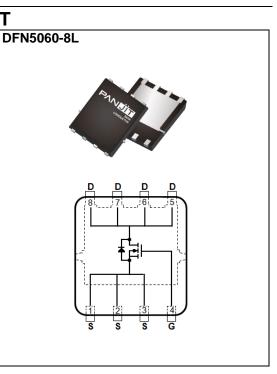
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<1.7m\Omega$

30 V

- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@20A<2.6m\Omega$
- Excellent FOM
- Logic Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETE | R | SYMBOL | LIMIT | UNITS |
|--|----------------------|------------------|---------|--------|
| Drain-Source Voltage | | V _{DS} | 30 | V |
| Gate-Source Voltage | | V _{GS} | ±20 | |
| Continuous Drain Current ^(Note 3) | T _C =25°C | | 152 | |
| | Tc=100°C | I _D | 108 | А |
| Pulsed Drain Current ^(Note 1) | T _C =25°C | I _{DM} | 608 | |
| Power Dissipation | T _C =25°C | D- | 79 | 14/ |
| | Tc=100°C | PD | 39.5 | W |
| Continuous Drain Current(Note 4) | T _A =25°C | | 31 | ^ |
| Continuous Drain Current ^(Note 4) | T _A =70°C | I _D | 26 | — A |
| Power Dissipation | T _A =25°C | Pp | 3.3 | W |
| | T _A =70°C | PD | 2.3 | vv |
| Single Pulse Avalanche Energy ^{(Note} | 9 5) | Eas | 81 | mJ |
| Operating Junction and Storage Te | emperature Range | TJ,TSTG | -55~175 | °C |
| Thermal Resistance ^(Note 4) | Junction to Case | R _{θJC} | 1.9 | °C/W |
| | Junction to Ambient | R _{θJA} | 45 | - C/VV |



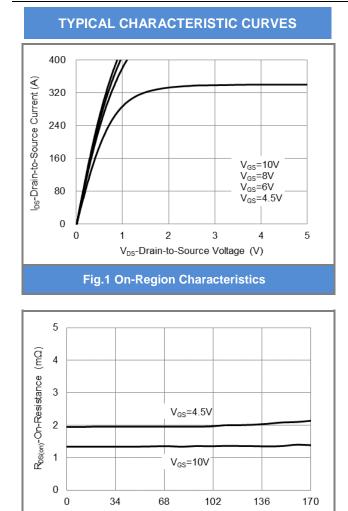
Electrical Characteristics (TA=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---------------------|--|------|------|------|-------|--|
| Static | | | • | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 30 | - | - | V | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250uA | 1.3 | 1.8 | 2.5 | | |
| Drain-Source On-State Resistance | | V _{GS} =10V, I _D =20A | - | 1.37 | 1.7 | | |
| | R _{DS(on)} | V _{GS} =4.5V, I _D =20A | - | 1.97 | 2.6 | mΩ | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =30V, V_{GS} =0V | - | - | ±1 | uA | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA | |
| Dynamic ^(Note 6) | | | | | | | |
| Total Gate Charge | Qg | | - | 45 | - | | |
| Gate-Source Charge | Qgs | V _{DS} =24V, I _D =20A, | - | 7.6 | - | nC | |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 6.6 | - | | |
| Input Capacitance | Ciss | | - | 2936 | - | pF | |
| Output Capacitance | Coss | V _{DS} =25V, V _{GS} =0V, f=1MHz | - | 1304 | - | | |
| Reverse Transfer Capacitance | Crss | I= IIVIHZ | - | 97 | - | | |
| Gate resistance | Rg | f=1MHz | - | 0.7 | - | Ω | |
| Turn-On Delay Time | td(on) | | - | 18 | - | | |
| Turn-On Rise Time | tr | V _{DS} =24V, I _D =20A, | - | 91 | - | | |
| Turn-Off Delay Time | td _(off) | V _{GS} =10V, R _G =3Ω | - | 69 | - | ns | |
| Turn-Off Fall Time | tf | | - | 32 | - | | |
| Drain-Source Diode | · | | | | | | |
| Diode Forward Current | Is | T 05°0 | - | - | 152 | | |
| Pulsed Diode Forward Current | I _{SM} | T _c =25°C | - | - | 608 | A | |
| Diode Forward Voltage | V _{SD} | Is=20A, V _{GS} =0V | - | 0.77 | 1.1 | V | |
| Reverse Recovery Time | Trr | V _{GS} =0V, I _S =20A | - | 31 | - | ns | |
| Reverse Recovery Charge | Qrr | dls/dt=100A/us | - | 62 | - | nC | |

NOTES :

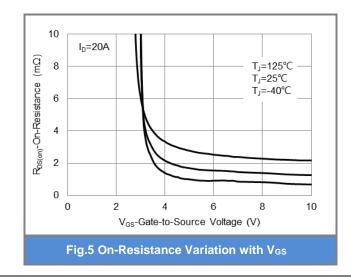
- 1. Pulse width \leq 100us, Duty cycle \leq 2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}$ =1.9°C/W, Package limited 100A.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =18A, V_{DD} =30V, V_{GS} =10V, Starting T_J =25°C. the chip is about to carry I_{AS} ≈36A.
- 6. Guaranteed by design, not subject to production testing.







IDS-Drain-to-Source Current (A)



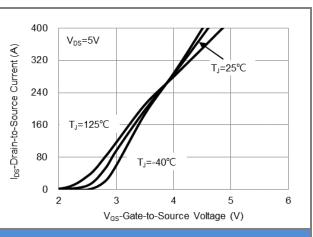


Fig.2 Transfer Characteristics

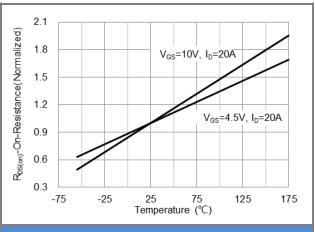
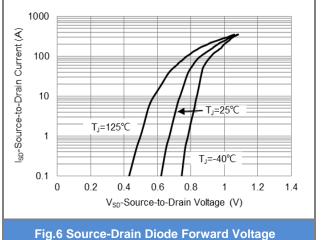
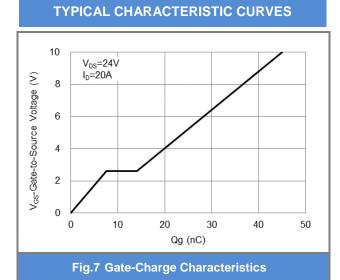
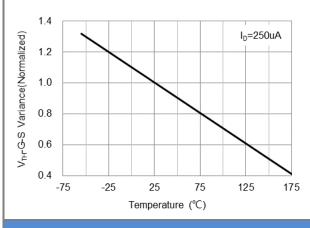


Fig.4 On-Resistance vs. Junction temperature

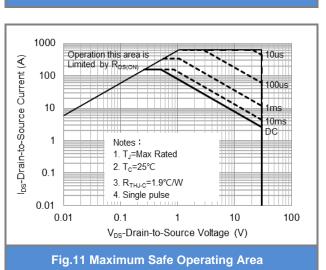


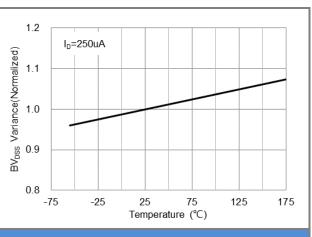














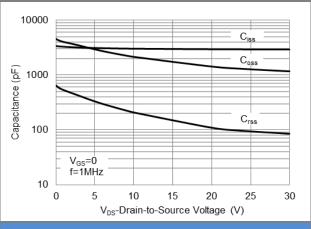
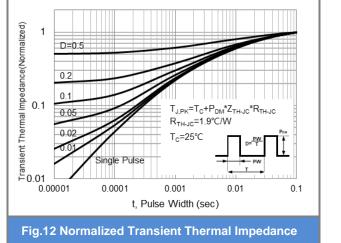


Fig.10 Capacitance vs. Drain-Source Voltage

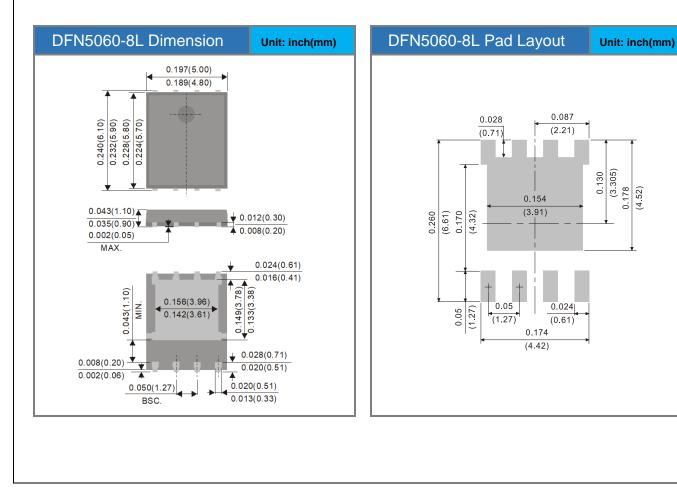




Product and Packing Information

| Part No. | Package Type | Packing Type | Marking |
|------------|--------------|-------------------|---------|
| PJQ5520-AU | DFN5060-8L | 3K pcs / 13" reel | Q5520 |

Packaging Information & Mounting Pad Layout





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